

**Self-Oscillating Half-Bridge Driver**

**Features**

- Floating channel designed for bootstrap operation
- Integrated 600V half-bridge gate driver
- 15.6V zener clamp on Vcc
- True micropower start up
- Tighter initial dead time control
- Low temperature coefficient dead time
- Shutdown feature (1/6th Vcc) on CT pin
- Increased undervoltage lockout Hysteresis (1V)
- Lower power level-shifting circuit
- Constant LO, HO pulse widths at startup
- Lower di/dt gate driver for better noise immunity
- Low side output in phase with RT
- Excellent latch immunity on all inputs and outputs
- ESD protection on all leads

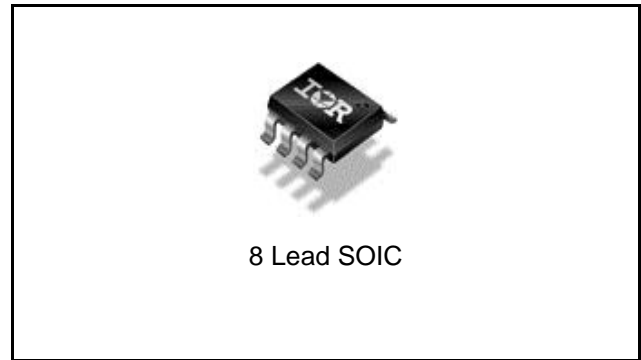
**Product Summary**

V <sub>OFFSET</sub>	600V max.
Duty Cycle	50%
T <sub>r</sub> / T <sub>f</sub>	80 / 40 ns
V <sub>CLAMP</sub>	15.6V
Dead time (typ.)	1.2 μs

**Description**

The IR25603(S) incorporates a high voltage half-bridge gate driver with a front end oscillator similar to the industry standard CMOS 555 timer. A shutdown feature has been designed into the CT pin, so that both gate driver outputs can be disabled using a low voltage control signal. In addition, the gate driver output pulse widths are the same once the rising undervoltage lockout threshold on Vcc has been reached, resulting in a more stable profile of frequency vs time at startup. Special attention has been paid to maximizing the latch immunity of the device and providing comprehensive ESD protection on all pins.

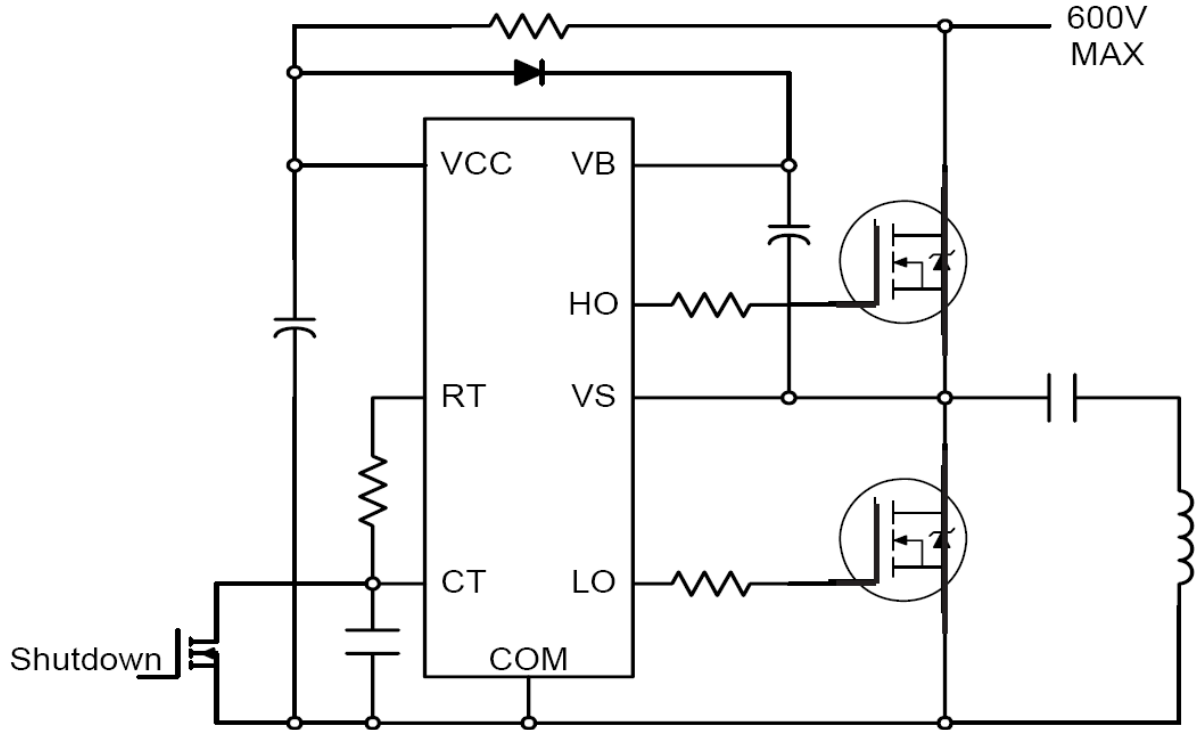
**Package Options**



**Ordering Information**

Base Part Number	Package Type	Standard Pack		Orderable Part Number
		Form	Quantity	
IR25603SPBF	SO8N	Tube	95	IR25603SPBF
IR25603SPBF	SO8N	Tape and Reel	2500	IR25603STRPBF

**Typical Connection Diagram**



## Absolute Maximum Ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM, all currents are defined positive into any lead. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

Symbol	Definition	Min.	Max.	Units
$V_B$	High side floating absolute voltage	-0.3	625	V
$V_S$	High side floating supply offset voltage	$V_B - 25$	$V_B + 0.3$	
$V_{HO}$	High side floating output voltage	$V_S - 0.3$	$V_B + 0.3$	
$V_{LO}$	Low side output voltage	-0.3	$V_{CC} + 0.3$	
$V_{CC}$	Low side and logic fixed supply voltage	-0.3	25	
$V_{RT}$	$R_T$ pin voltage	-0.3	$V_{CC} + 0.3$	
$V_{CT}$	$C_T$ pin voltage	-0.3	$V_{CC} + 0.3$	
$I_{CC}$	Supply current†	—	25	mA
$I_{RT}$	$R_T$ pin current	-5	5	V/ns
$dV_S/dt$	Allowable offset supply voltage transient	—	50	
$P_D$	Package power dissipation @ $T_A \leq +25^\circ\text{C}$	—	0.625	W
$R_{thJA}$	Thermal resistance, junction to ambient	—	200	$^\circ\text{C}/\text{W}$
$T_J$	Junction temperature	—	150	$^\circ\text{C}$
$T_S$	Storage temperature	-55	150	
$T_L$	Lead temperature (soldering, 10 seconds)	—	300	

## Recommended Operating Conditions

For proper operation the device should be used within the recommended conditions. The  $V_S$  offset rating is tested with all supplies biased at 15V differential.

Symbol	Definition	Min.	Max.	Units
$V_B$	High side floating supply absolute voltage	$V_{CC} - 0.7$	$V_{CLAMP}$	V
$V_S$	Steady state high side floating supply offset voltage	††	600	
$V_{CC}$	Supply voltage	10	$V_{CLAMP}$	
$I_{CC}$	Supply current	†††	5	mA
$T_A$	Ambient temperature	-40	125	$^\circ\text{C}$

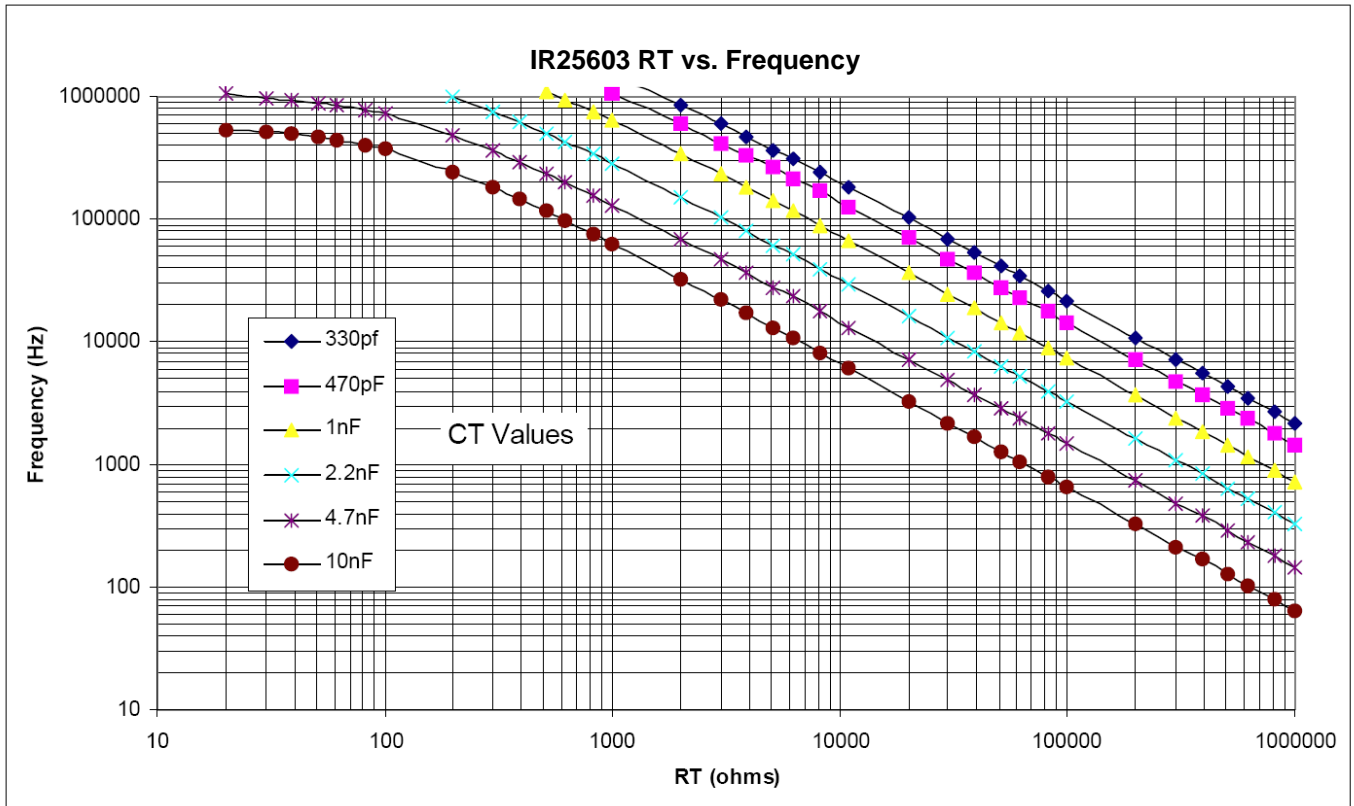
† This IC contains a zener clamp structure between the chip  $V_{CC}$  and COM which has a nominal breakdown voltage of 15.6V. Please note that this supply pin should not be driven by a DC, low impedance power source greater than the  $V_{CLAMP}$  specified in the Electrical Characteristics section.

†† Care should be taken to avoid output switching conditions where the  $V_S$  node flies inductively below ground by more than 5V.

††† Enough current should be supplied to the  $V_{CC}$  pin of the IC to keep the internal 15.6V zener diode clamping the voltage at this pin.

**Recommended Component Values**

Symbol	Component	Min.	Max.	Units
$R_T$	Timing resistor value	10	—	$k\Omega$
$C_T$	$C_T$ pin capacitor value	330	—	$\mu F$



## Electrical Characteristics

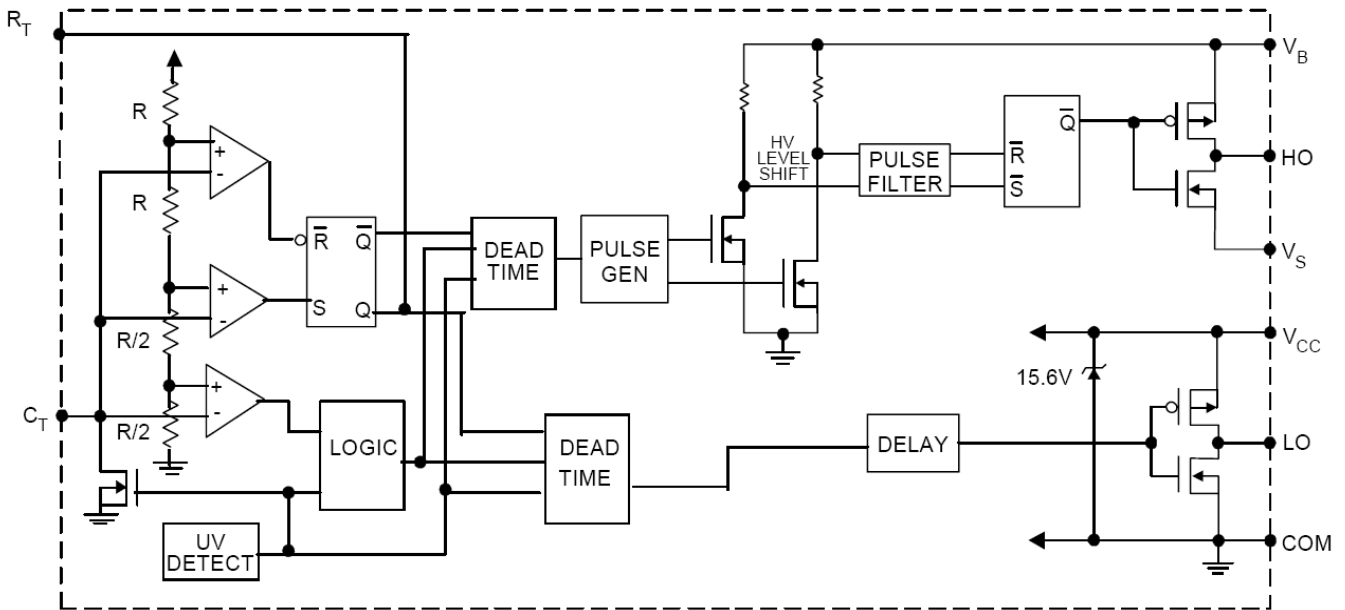
$V_{BIAS}$  ( $V_{CC}$ ,  $V_{BS}$ ) = 12V,  $C_L$  = 1000 pF,  $C_T$  = 1nF and  $T_A$  = 25°C unless otherwise specified.

Low Voltage Supply Characteristics						
Symbol	Definition	Min.	Typ.	Max.	Units	Test Conditions
$V_{CCUV+}$	$V_{CC}$ supply undervoltage positive going threshold	8.1	9.0	9.9	V	
$V_{CCUV-}$	$V_{CC}$ supply undervoltage negative going threshold	7.2	8.0	8.8		
$V_{CCUVH}$	$V_{CC}$ undervoltage hysteresis	0.5	1.0	1.5		
$I_{QCCUV}$	Micropower startup $V_{CC}$ supply current	—	75	150	uA	$V_{CC} \leq V_{CCUV-}$
$I_{QCC}$	Quiescent $V_{CC}$ supply current	—	500	950		
$V_{CLAMP}$	$V_{CC}$ zener clamp voltage	14.4	15.6	16.8	V	$I_{CC} = 5mA$
Floating Supply Characteristics						
Symbol	Definition	Min.	Typ.	Max.	Units	Test Conditions
$I_{QBSUV}$	Micropower startup $V_{BS}$ supply current	—	0	10	uA	$V_{CC} \leq V_{CCUV-}$
$I_{QBS}$	Quiescent $V_{BS}$ supply current	—	30	50		
$V_{BSMIN}$	Minimum required $V_{BS}$ voltage for proper functionality from $R_T$ to HO	—	4.0	5.0	V	$V_{CC} = V_{CCUV+} + 0.1V$
$I_{LK}$	Offset supply leakage current	—	—	50	uA	$V_B = V_S = 600V$
Oscillator I/O Characteristics						
Symbol	Definition	Min.	Typ.	Max.	Units	Test Conditions
$f_{OSC}$	Oscillator frequency	19.4	20	20.6	kHz	$R_T = 36.9k\Omega$
		94	100	106		$R_T = 7.43k\Omega$
$d$	$R_T$ pin duty cycle	48	50	52	%	$f_O < 100kHz$
$I_{CT}$	$C_T$ pin current	—	0.001	1.0	uA	
$I_{CTUV}$	UV-mode $C_T$ pin pulldown current	0.3	0.7	1.2	mA	$V_{CC} = 7V$
$V_{CT+}$	Upper $C_T$ ramp voltage threshold	—	8	—	V	
$V_{CT-}$	Lower $C_T$ ramp voltage threshold	—	4	—		
$V_{CTSD}$	$C_T$ voltage shutdown threshold	1.8	2.1	2.4		
$V_{RT+}$	High-level $R_T$ output voltage, $V_{CC} - V_{RT}$	—	10	50	mV	$I_{RT} = 100 \mu A$
		—	100	300		$I_{RT} = 1mA$
$V_{RT-}$	Low-level $R_T$ output voltage	—	10	50		$I_{RT} = 100 \mu A$
		—	100	300		$I_{RT} = 1mA$
$V_{RTUV}$	UV-mode $R_T$ output voltage		0	100		$V_{CC} \leq V_{CCUV-}$
$V_{RTSD}$	SD-Mode $R_T$ output voltage, $V_{CC} - V_{RT}$	—	10	50		$I_{RT} = 100 \mu A,$ $V_{CT} = 0V$
		—	10	300		$I_{RT} = 1mA,$ $V_{CT} = 0V$

**Electrical Characteristics (cont.)**

Gate Driver Output Characteristics						
Symbol	Definition	Min.	Typ.	Max.	Units	Test Conditions
VOH	High level output voltage, $V_{BIAS} - V_O$	—	0	100	mV	$I_O = 0A$
VOL	Low-level output voltage, $V_O$	—	0	100		$I_O = 0A$
VOL_UV	UV-mode output voltage, $V_O$	—	0	100		$I_O = 0A$ $V_{CC} \leq V_{CCUV-}$
$t_r$	Output rise time	—	80	150	ns	
$t_f$	Output fall time	—	45	100		
$t_{sd}$	Shutdown propagation delay	—	660	—		
$t_d$	Output dead time (HO or LO)	0.75	1.20	1.65	$\mu s$	

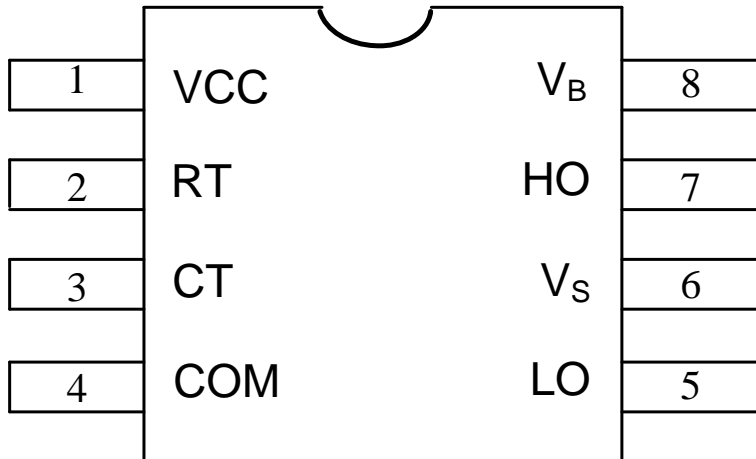
**Functional Block Diagram**



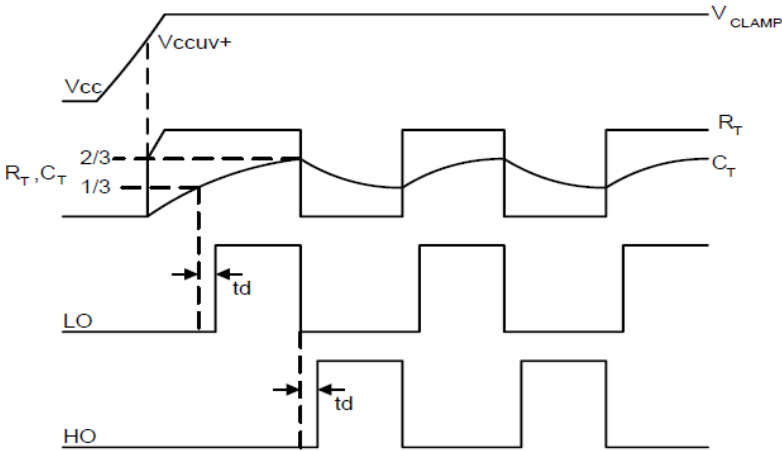
**Lead Definitions**

Symbol	Description
V <sub>CC</sub>	Logic and internal gate drive supply voltage
R <sub>T</sub>	Oscillator timing resistor input
C <sub>T</sub>	Oscillator timing capacitor input
COM	IC power and signal ground
LO	Low side gate driver output
V <sub>S</sub>	High voltage floating supply return
HO	High side gate driver output
V <sub>B</sub>	High side gate driver floating supply

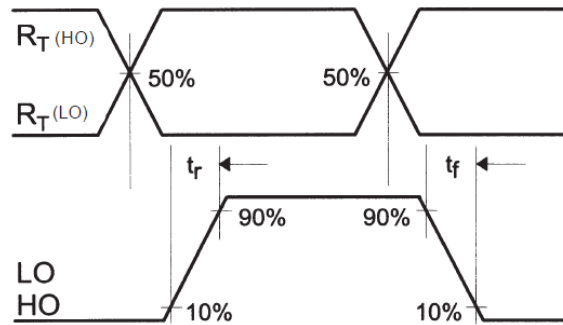
**Lead Assignments**



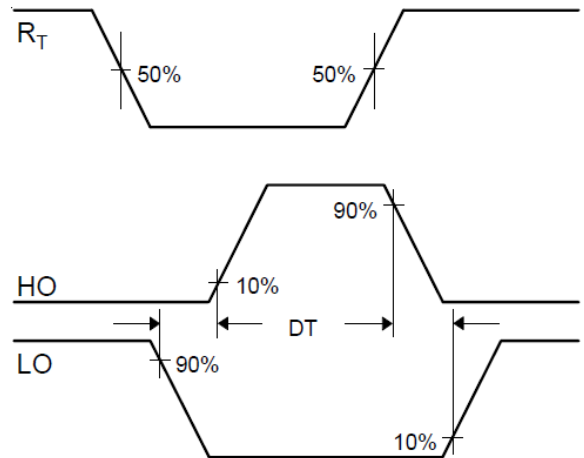
**Advance Information**



**Figure 1. Input/Output Timing Diagram**

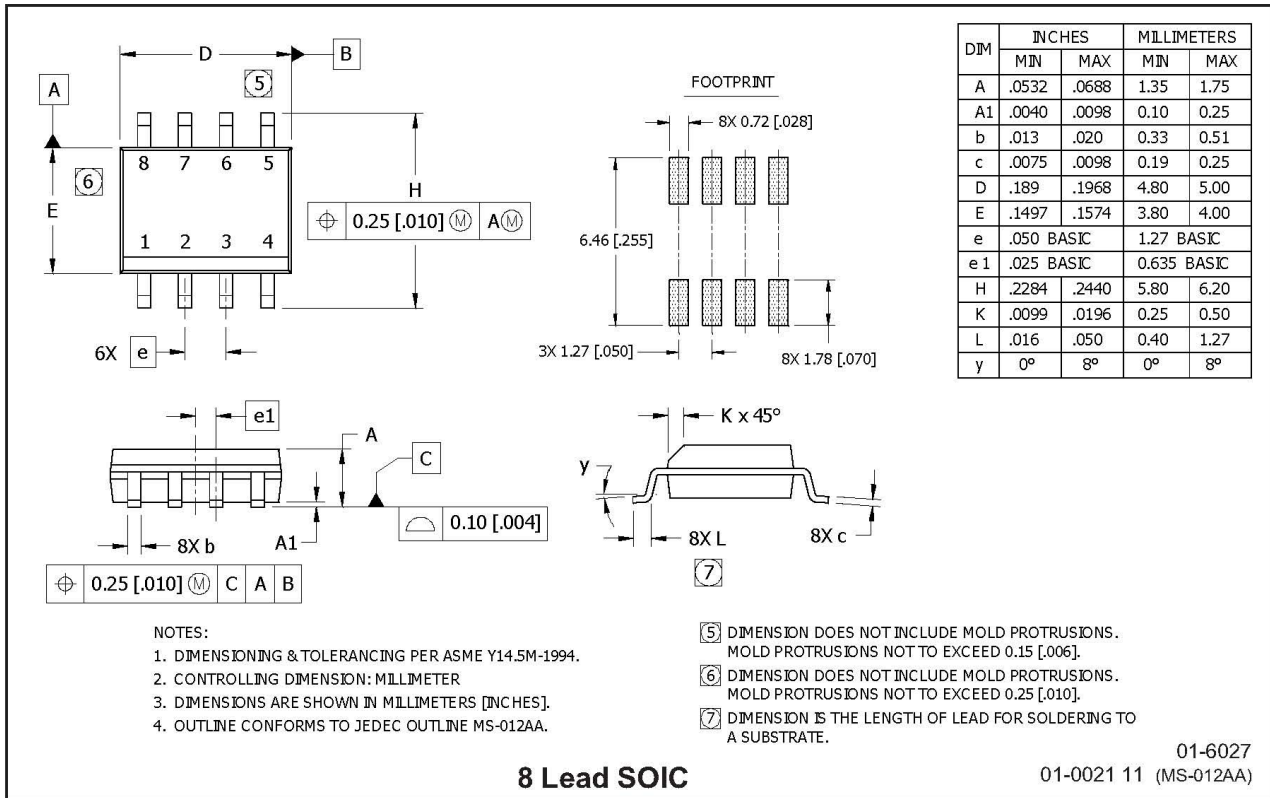


**Figure 2. Switching Time Waveform Definitions**



**Figure 3. Deadtime Waveform Definitions**



**Package Details**

**NOTES:**

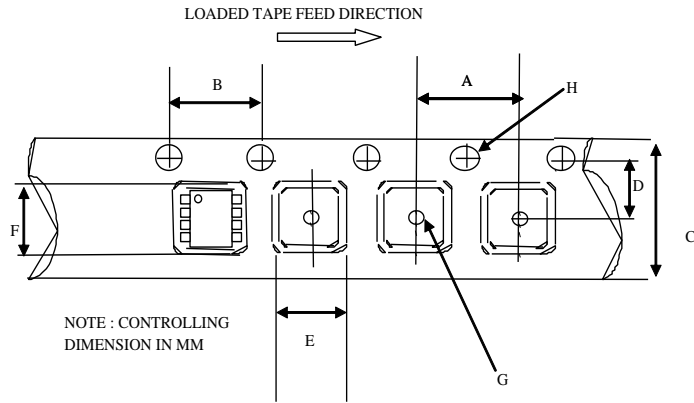
1. DIMENSIONING & TOLERANCING PER ASME Y14.5M-1994.
2. CONTROLLING DIMENSION: MILLIMETER
3. DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES].
4. OUTLINE CONFORMS TO JEDEC OUTLINE MS-012AA.

⑤ DIMENSION DOES NOT INCLUDE MOLD PROTRUSIONS. MOLD PROTRUSIONS NOT TO EXCEED 0.15 [0.006].

⑥ DIMENSION DOES NOT INCLUDE MOLD PROTRUSIONS. MOLD PROTRUSIONS NOT TO EXCEED 0.25 [0.010].

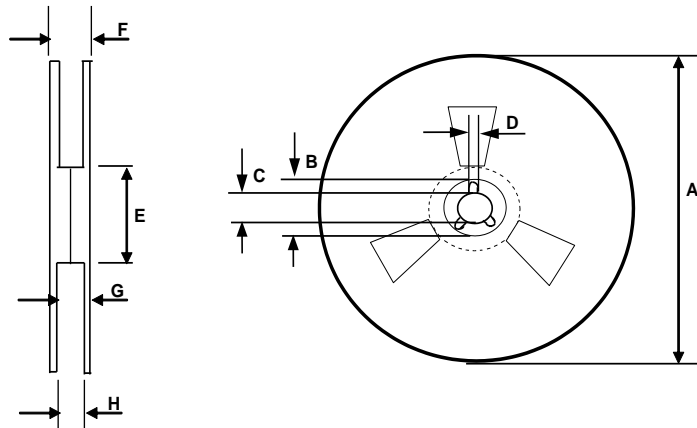
⑦ DIMENSION IS THE LENGTH OF LEAD FOR SOLDERING TO A SUBSTRATE.

## Tape and Reel Details



CARRIER TAPE DIMENSION FOR 8SOICN

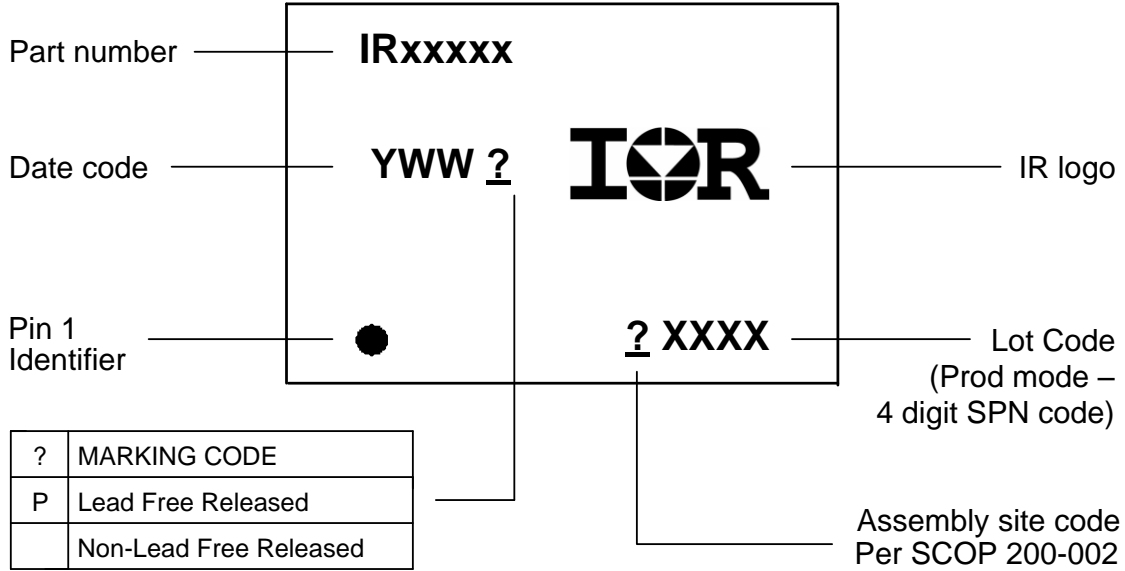
Code	Metric		Imperial	
	Min	Max	Min	Max
A	7.90	8.10	0.311	0.318
B	3.90	4.10	0.153	0.161
C	11.70	12.30	0.46	0.484
D	5.45	5.55	0.214	0.218
E	6.30	6.50	0.248	0.255
F	5.10	5.30	0.200	0.208
G	1.50	n/a	0.059	n/a
H	1.50	1.60	0.059	0.062



REEL DIMENSIONS FOR 8SOICN

Code	Metric		Imperial	
	Min	Max	Min	Max
A	329.60	330.25	12.976	13.001
B	20.95	21.45	0.824	0.844
C	12.80	13.20	0.503	0.519
D	1.95	2.45	0.767	0.096
E	98.00	102.00	3.858	4.015
F	n/a	18.40	n/a	0.724
G	14.50	17.10	0.570	0.673
H	12.40	14.40	0.488	0.566

**Part Marking Information**



**Qualification Information<sup>†</sup>**

<b>Qualification Level</b>	Industrial <sup>††</sup> (per JEDEC JESD 47E)
	Comments: This family of ICs has passed JEDEC's Industrial qualification. IR's Consumer qualification level is granted by extension of the higher Industrial level.
<b>Moisture Sensitivity Level</b>	MSL2 <sup>†††</sup> (per IPC/JEDEC J-STD-020C)
<b>RoHS Compliant</b>	Yes

- † Qualification standards can be found at International Rectifier's web site <http://www.irf.com/>
- †† Higher qualification ratings may be available should the user have such requirements. Please contact your International Rectifier sales representative for further information.
- ††† Higher MSL ratings may be available for the specific package types listed here. Please contact your International Rectifier sales representative for further information.

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